



## 2SB1143/2SD1683

### 50V/4A Switching Applications

#### Applications

- Voltage regulators, relay drivers, lamp drivers, electrical equipment.

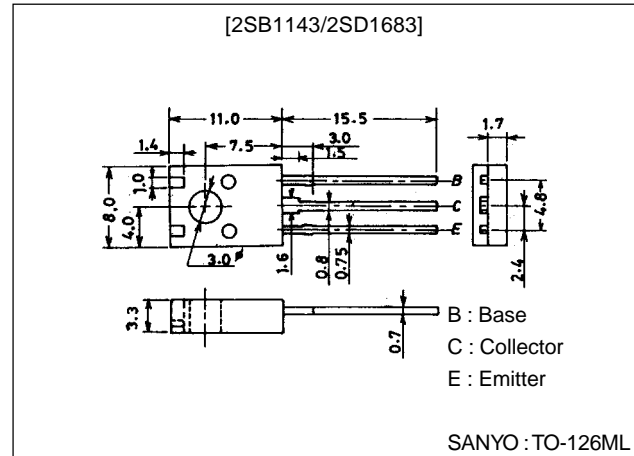
#### Features

- Adoption of FBET, MBIT processes.
- Low saturation voltage.
- Large current capacity and wide ASO.

#### Package Dimensions

unit:mm

2042A



() : 2SB1143

#### Specifications

##### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	$V_{CB0}$		(-)60	V
Collector-to-Emitter Voltage	$V_{CEO}$		(-)50	V
Emitter-to-Base Voltage	$V_{EBO}$		(-)6	V
Collector Current	$I_C$		(-)4	A
Collector Current (Pulse)	$I_{CP}$		(-)6	A
Collector Dissipation	$P_C$		1.5	W
		$T_c=25^\circ\text{C}$	10	W
Junction Temperature	$T_j$		150	°C
Storage Temperature	$T_{stg}$		-55 to +150	°C

##### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	$I_{CBO}$	$V_{CB}=(-)40\text{V}, I_E=0$			(-)1	$\mu\text{A}$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB}=(-)4\text{V}, I_C=0$			(-)1	$\mu\text{A}$
DC Current Gain	$h_{FE1}$	$V_{CE}=(-)2\text{V}, I_C=(-)100\text{mA}$	100*		560*	
	$h_{FE2}$	$V_{CE}=(-)2\text{V}, I_C=(-)3\text{A}$	40			
Gain-Bandwidth Product	$f_T$	$V_{CE}=(-)10\text{V}, I_C=(-)50\text{mA}$		150		MHz
Output Capacitance	$C_{ob}$	$V_{CB}=(-)10\text{V}, f=1\text{MHz}$		(39)25		pF

\* ; The 2SB1143/2SD1683 are classified by 100mA  $h_{FE}$  as follows :

100 R	200	140 S	280	200 T	400	280 U	560
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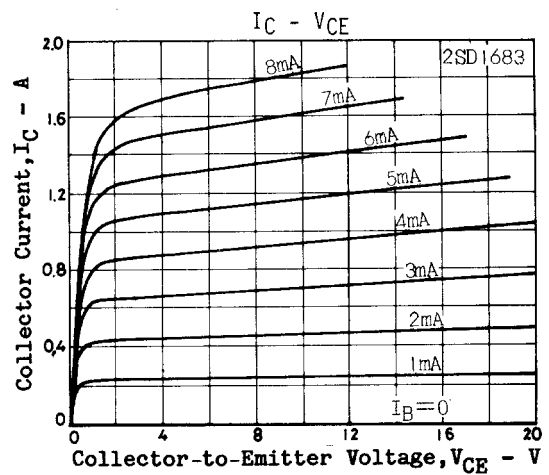
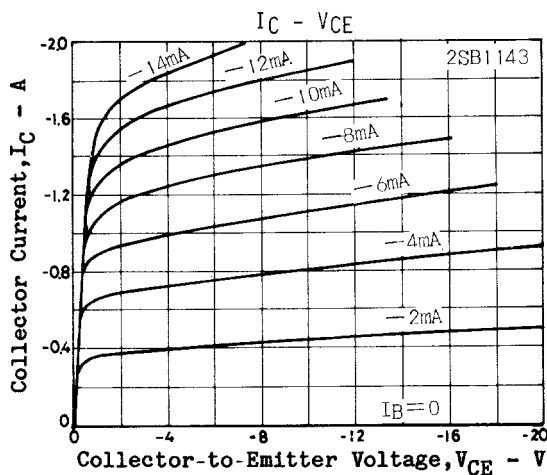
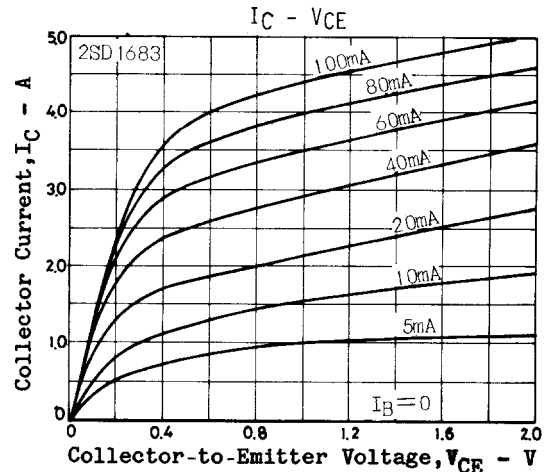
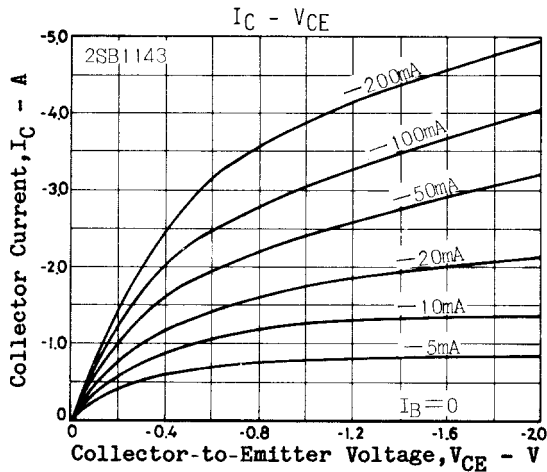
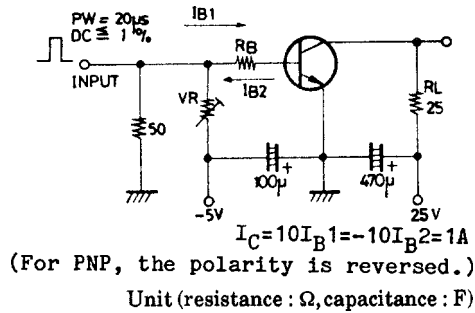
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92098HA (KT)/4137KI/D176TA, TS No.2063-1/4

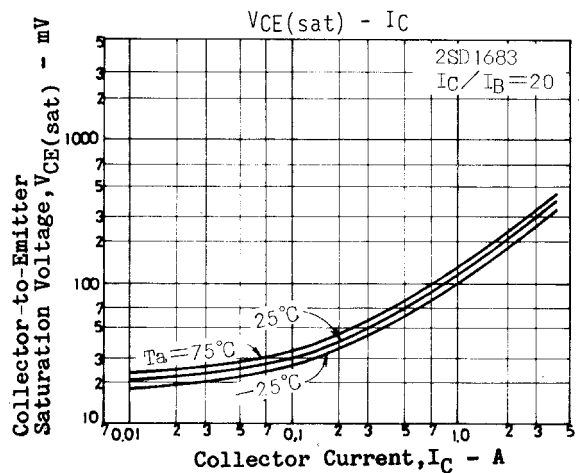
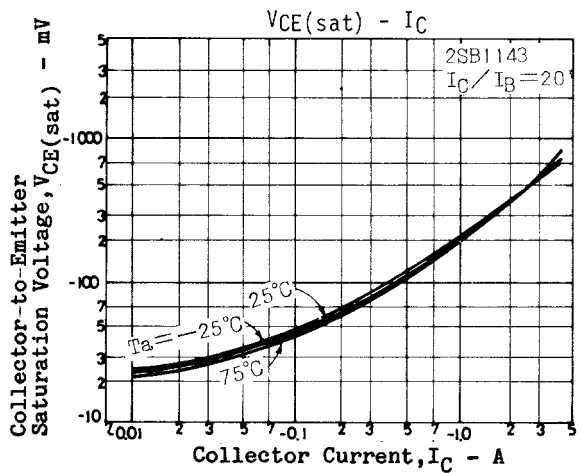
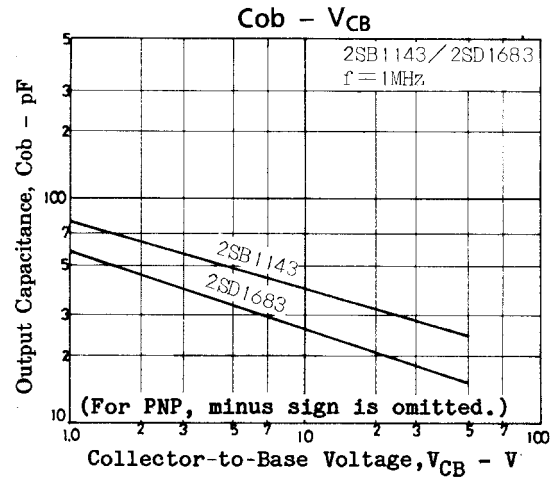
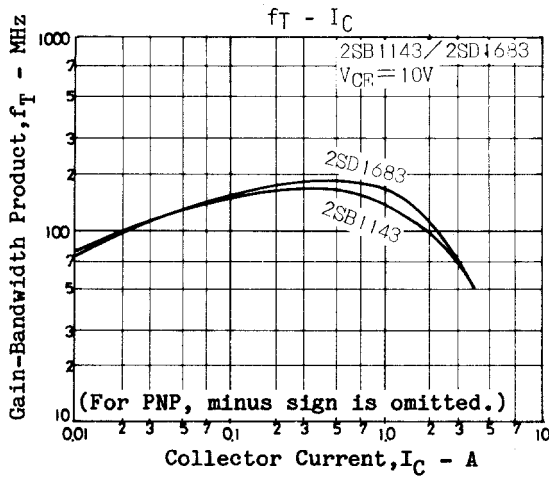
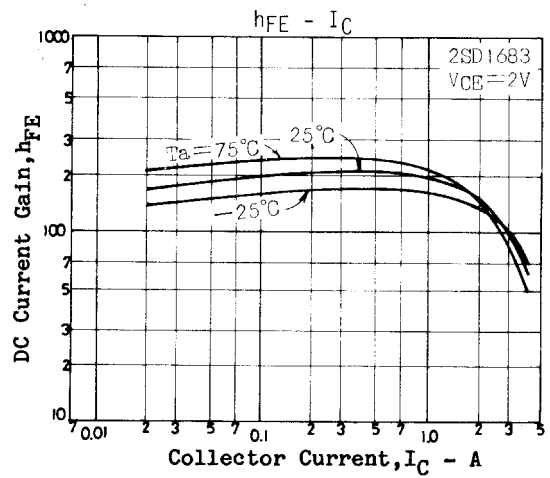
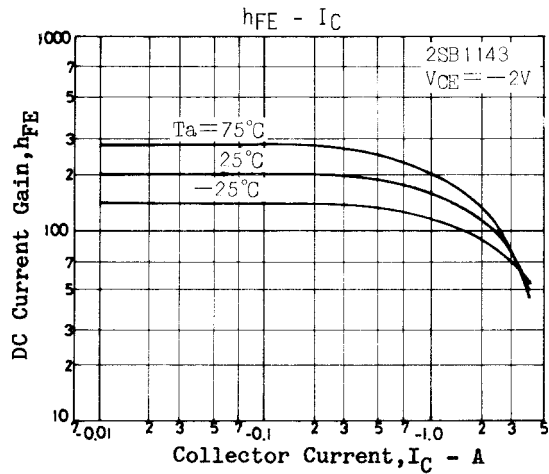
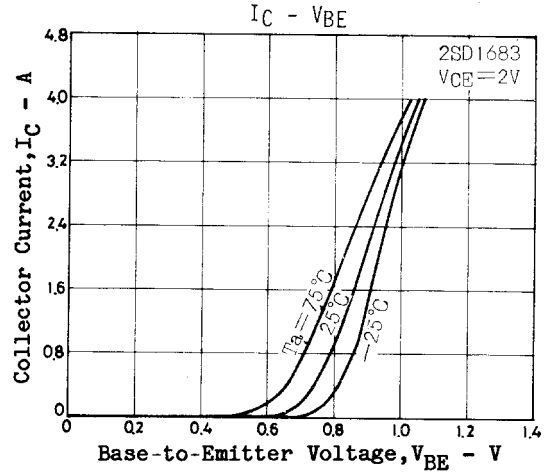
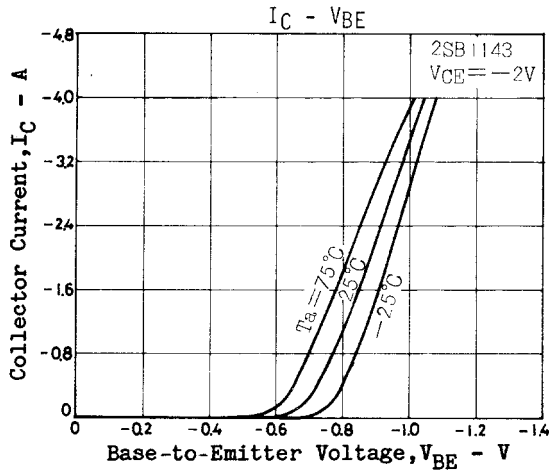
## 2SB1143/2SD1683

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)2A, I_B=(-)100mA$		(-350)	(-700)	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)2A, I_B=(-)100mA$		(-0.94)	(-1.2)	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-60)			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-50)			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$	(-6)			V
Turn-ON Time	$t_{on}$	See specified Test Circuit		(70)70		ns
Storage Time	$t_{stg}$	See specified Test Circuit		(450)		ns
				650		ns
Fall Time	$t_f$	See specified Test Circuit		(30)35		ns

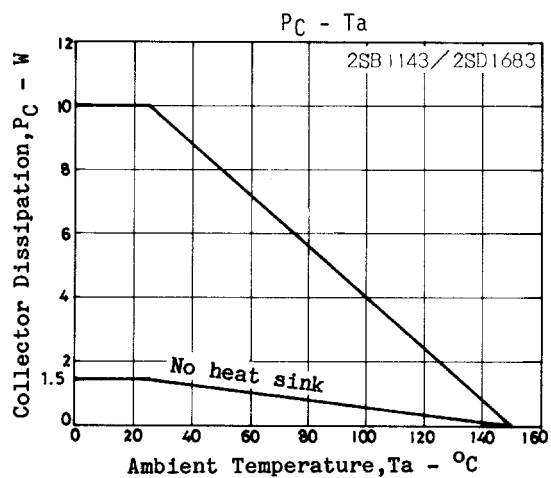
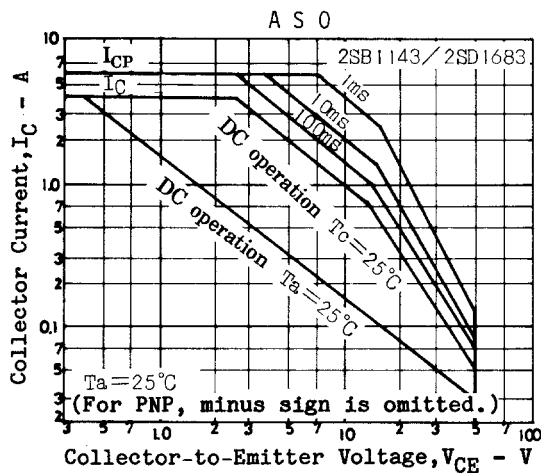
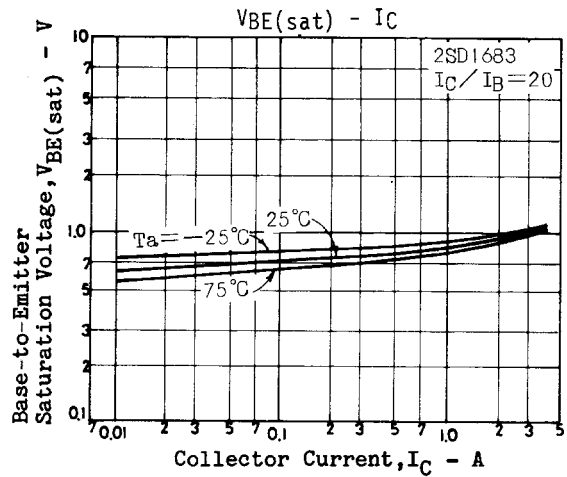
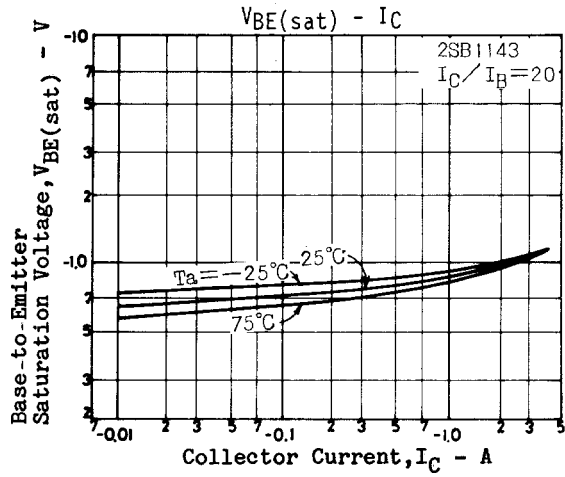
### Switching Time Test Circuit



# 2SB1143/2SD1683



## 2SB1143/2SD1683



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